

PRODUCT SELECTION GUIDE

Samsung Semiconductor, Inc.

MEMORY & STORAGE

2H 2010





Samsung Semiconductor, Inc.

Samsung offers the industry's broadest memory portfolio and has maintained its leadership in memory technology for 16 straight years. Its DRAM, flash and SRAM products are found in computers—from ultra-mobile portables to powerful servers—and in a wide range of handheld devices such as smartphones and MP3 players. Samsung also delivers the industry's widest line of storage products. These include optical and hard disk drives as well as flash storage, such as the all-flash Solid State Drive and a range of embedded and removable flash storage products.

| Markets | DRAM | SRAM | FLASH | ASIC | LOGIC | TFT/LCD | ODD/HDD |
|-----------------------------|------|------|-------|------|-------|---------|---------|
| Mobile/Wireless | ı | | | | | | |
| Notebook PCs | ı | | | ı | | | |
| Desktop PCs/Workstations | | | | | | | |
| Servers | | | | | | | |
| Networking/ Communications | | | | | | | |
| Consumer Electronics | ı | | | ı | | | |



DRAM

www.samsung.com/semi/dram

- DDR3 SDRAM
- DDR2 SDRAM
- DDR SDRAM
- SDRAM
- Mobile SDRAM
- RDRAM

• Graphics DDR SDRAM

• DRAM Ordering Information

Pages 14-16 **FLASH**

www.samsung.com/semi/flash

- SLC Flash
- MLC Flash
- SD and microSD Cards

• Flash Ordering Information

HIGH SPEED SRAM

Pages 17-20

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www.samsung.com/semi/sram

- Asychronous
- Synchronous
- NtRAM™
- Late-Write R-R SRAM
- DDR / II / II+ SRAM
- QDR / II / II+ SRAM

MULTI-CHIP PACKAGE

Pages 21-22

www.samsung.com/semi/mcp

- NAND & DRAM
- OneNAND & DRAM
- Flex-OneNAND & DRAM
- OneNAND & DRAM & OneDRAM
- moviNAND & NAND & DRAM
- NOR & UtRAM NOR & DRAM

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www.samsung.com/semi/fusion

moviNAND™

Fusion Memory

OneDRAM™

Pages 24-27 **STORAGE**

SSD

www.samsungssd.com

SATA SSD

Hard Drive

www.samsung.com/hdd

Optical Disc

www.samsungodd.com

DDR3 SDRAM REGISTERED MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|----------------------------------|-------------------------|--------------------------|--------------|-------|------------|
| 1GB | 1.5V | 128Mx72 | M393B2873FH0-C(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 2GB | 1.5V | 256Mx72 | M393B5673FH0-C(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| ZUD | 1.00 | 230IVIX/2 | M393B5670FH0-C(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | | M393B5173FH0-CF8(04/05) | 1Gb (128M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 4GB | 1.5\/ | 512Mx72 | M393B5170FH0-C(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 4GD | 1.5V | 312IVIX/Z | M393B5273CH0-C(F8/H9/K0*)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | | M393B5270CH0-C(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 8GB | 1.5V | 1Gx72 | M393B1K73CH0-CF8(04/05) | 2Gb (256M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| OUD | 1.50 | IUX/Z | M393B1K70CH0-C(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 16GB | 1.5V | 2Gx72 | M393B2K70CM0-CF8(04/05) | 4Gb DDP (1024M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 32GB | 1.5V | 4Gx72 | M393B4G70AM0-CF8(04/05) | 8Gb DDP (2048M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 1GB | 1.35V | 128Mx72 | M393B2873FH0-Y(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 2GB | 1.35V | 256Mx72 | M393B5673FH0-Y(F8/H9/K0*)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| ZUD | 1.337 | 230IVIX/ 2 | M393B5670FH0-Y(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | | M393B5173FH0-YF8(04/05) | 1Gb (128M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 4GB | 1.35V | 512Mx72 | M393B5170FH0-Y(F8/H9/K0*)(04/05) | 1Gb (256M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 400 | 1.554 | JIZIVIXIZ | M393B5273CH0-Y(F8/H9/K0*)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | | M393B5270CH0-Y(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 8GB | 1.35V | 1Gx72 | M393B1K73CH0-YF8(04/05) | 2Gb (256M x8) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| OUD | 1.33V | TUX/Z | M393B1K70CH0-Y(F8/H9/K0*)(04/05) | 2Gb (512M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 16GB | 1.35V | 2Gx72 | M393B2K70CM0-YF8(04/05) | 4Gb DDP (1024M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 32GB | 1.35V | 4Gx72 | M393B4G70AM0-YF8(04/05) | 8Gb DDP (2048M x4) * 36 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |

NOTES:

F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7)

H9 = DDR3-1333 (9-9-9) K0 = DDR3-1600 (11-11-11)

04 = IDT B0 register 05 = Inphi C0 register * K0 (1600Mbps) available in ES only

DDR3 SDRAM VLP REGISTERED MODULES

| Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|-------------|--|--|---|---|---|---|---|
| 1.5V | 128Mx72 | M392B2873FH0-C(F8/H9)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 1 51/ | 0E6Mv70 | M392B5673FH0-C(F8/H9)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| VC.1 | 230IVIX72 | M392B5670FH0-C(F8/H9)(04/05) | 1Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | M392B5170FM0-C(F8/H9)(04/05) | 2Gb DDP (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1.5V | 512Mx72 | M392B5273CH0-C(F8/H9)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | M392B5270CH0-C(F8/H9)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 1 5\/ | 10,70 | M392B1K73CM0-CF8(04/05) | 4Gb DDP (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| VG.1 | TGX/Z | M392B1K70CM0-C(F8/H9)(04/05) | 4Gb DDP (1024M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1.5V | 2Gx72 | M392B2G70AM0-C(F8/H9)(04/05) | 8Gb DDP (2048M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1.35V | 128Mx72 | M392B2873FH0-Y(F8/H9)(04/05) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 1 051/ | 0E6Mv70 | M392B5673FH0-Y(F8/H9)(04/05) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1.337 | 230IVIX/2 | M392B5670FH0-Y(F8/H9)(04/05) | 1Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| | | M392B5170FM0-Y(F8/H9)(04/05) | 2Gb DDP (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1.35V | 512Mx72 | M392B5273CH0-Y(F8/H9)(04/05) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | | M392B5270CH0-Y(F8/H9)(04/05) | 2Gb (512M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 1 | Now |
| 1 251/ | 10v70 | M392B1K73CM0-YF8(04/05) | 4Gb DDP (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333 | 4 | Now |
| 1.35V 1Gx/2 | IUX/Z | M392B1K70CM0-Y(F8/H9)(04/05) | 4Gb DDP (1024M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| 1.35V | 2Gx72 | M392B2G70AM0-Y(F8/H9)(04/05) | 8Gb DDP (2048M x4) * 18 | Lead Free & Halogen Free | 1066/1333 | 2 | Now |
| | 1.5V 1.5V 1.5V 1.5V 1.35V 1.35V | 1.5V 128Mx72 1.5V 256Mx72 1.5V 512Mx72 1.5V 1Gx72 1.5V 2Gx72 1.35V 128Mx72 1.35V 512Mx72 1.35V 1Gx72 | 1.5V 128Mx72 M392B2873FH0-C(F8/H9)(04/05) 1.5V 256Mx72 M392B5673FH0-C(F8/H9)(04/05) 1.5V 512Mx72 M392B5670FH0-C(F8/H9)(04/05) 1.5V 512Mx72 M392B5273CH0-C(F8/H9)(04/05) 1.5V 16x72 M392B1K73CM0-CF8(04/05) 1.5V 26x72 M392B1K73CM0-C(F8/H9)(04/05) 1.35V 128Mx72 M392B2873FH0-Y(F8/H9)(04/05) 1.35V 256Mx72 M392B5673FH0-Y(F8/H9)(04/05) M392B5670FH0-Y(F8/H9)(04/05) M392B5670FH0-Y(F8/H9)(04/05) M392B5273CH0-Y(F8/H9)(04/05) M392B5273CH0-Y(F8/H9)(04/05) M392B1K73CM0-YF8(04/05) M392B1K73CM0-YF8(04/05) M392B1K70CM0-Y(F8/H9)(04/05) M392B1K70CM0-YF(F8/H9)(04/05) | 1.5V 128Mx72 M392B2873FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 9 1.5V 256Mx72 M392B5673FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 18 1.5V 256Mx72 M392B5670FH0-C(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 1.5V 512Mx72 M392B5273CH0-C(F8/H9)(04/05) 2Gb (256M x8) * 18 1.5V 1Gx72 M392B1K73CM0-CF8(04/05) 2Gb (512M x4) * 18 1.5V 2Gx72 M392B2G70AM0-C(F8/H9)(04/05) 4Gb DDP (1024M x4) * 18 1.5V 128Mx72 M392B2G70AM0-C(F8/H9)(04/05) 8Gb DDP (2048M x4) * 18 1.35V 128Mx72 M392B2G70AM0-C(F8/H9)(04/05) 1Gb (128M x8) * 9 1.35V 256Mx72 M392B2673FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 18 1.35V 256Mx72 M392B5673FH0-Y(F8/H9)(04/05) 1Gb (256M x8) * 18 1.35V 256Mx72 M392B5673FH0-Y(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 1.35V 392B5673FH0-Y(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 1.35V 392B5673CH0-Y(F8/H9)(04/05) 2Gb (256M x8) * 18 1.35V 400 DDP (512M x4) * 18 | 1.5V 128Mx72 M392B2873FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 9 Lead Free & Halogen Free 1.5V 256Mx72 M392B5673FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 18 Lead Free & Halogen Free M392B5670FH0-C(F8/H9)(04/05) 1Gb (256M x8) * 18 Lead Free & Halogen Free M392B5170FM0-C(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 Lead Free & Halogen Free M392B5273CH0-C(F8/H9)(04/05) 2Gb (256M x8) * 18 Lead Free & Halogen Free M392B5270CH0-C(F8/H9)(04/05) 2Gb (512M x4) * 18 Lead Free & Halogen Free M392B1K73CM0-CF8(04/05) 4Gb DDP (512M x8) * 18 Lead Free & Halogen Free M392B1K70CM0-C(F8/H9)(04/05) 4Gb DDP (1024M x4) * 18 Lead Free & Halogen Free 1.5V 2Gx72 M392B2G70AM0-C(F8/H9)(04/05) 4Gb DDP (2048M x4) * 18 Lead Free & Halogen Free 1.35V 128Mx72 M392B5673FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 9 Lead Free & Halogen Free M392B5670FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 18 Lead Free & Halogen Free M392B570CH0-Y(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 Lead Free & Halogen Free M392B5273CH0-Y(F8/H9)(04/05) 2Gb (512M x4) * 18 Lead Free & Halogen Free | 1.5V 128Mx72 M392B2873FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 9 Lead Free & Halogen Free 1066/1333 1.5V 256Mx72 M392B5673FH0-C(F8/H9)(04/05) 1Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 1.5V 256Mx72 M392B5670FH0-C(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 Lead Free & Halogen Free 1066/1333 1.5V 512Mx72 M392B5273CH0-C(F8/H9)(04/05) 2Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 1.5V 316X72 M392B1K73CM0-C(F8/H9)(04/05) 2Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 1.5V 2Gx72 M392B1K73CM0-C(F8/H9)(04/05) 4Gb DDP (512M x4) * 18 Lead Free & Halogen Free 1066/1333 1.5V 2Gx72 M392B1K70CM0-C(F8/H9)(04/05) 4Gb DDP (1024M x4) * 18 Lead Free & Halogen Free 1066/1333 1.5V 2Gx72 M392B2G70AM0-C(F8/H9)(04/05) 8Gb DDP (2048M x4) * 18 Lead Free & Halogen Free 1066/1333 1.35V 256Mx72 M392B2873FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 9 Lead Free & Halogen Free 1066/1333 1.35V 356Mx72 M392B5673FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 3512Mx72 M392B5673FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360Mx72 M392B573CH0-Y(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360Mx72 M392B573CH0-Y(F8/H9)(04/05) 2Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360Mx72 M392B573CH0-Y(F8/H9)(04/05) 2Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360Mx72 M392B573CH0-Y(F8/H9)(04/05) 2Gb (512M x4) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360M392B573CH0-Y(F8/H9)(04/05) 2Gb (512M x4) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360M392B570CH0-Y(F8/H9)(04/05) 4Gb DDP (512M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360M392B570CH0-Y(F8/H9)(04/05) 4Gb DDP (512M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360M392B570CH0-Y(F8/H9)(04/05) 4Gb DDP (512M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360M392B570CH0-Y(F8/H9)(04/05) 4Gb DDP (512M x8) * 18 Lead Free & Halogen Free 1066/1333 1.35V 360M392B1K70CM0-YF8/04/05) 4Gb DDP (1024M x4) * 18 Lead Free & Halogen Free 1066/1333 | 1.5V 128Mx72 M392B2873FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 9 Lead Free & Halogen Free 1066/1333 1 1.5V 256Mx72 M392B5673FH0-C(F8/H9)(04/05) 1Gb (128M x8) * 18 Lead Free & Halogen Free 1066/1333 2 1.5V M392B5670FH0-C(F8/H9)(04/05) 1Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 1 1.5V 512Mx72 M392B5273CH0-C(F8/H9)(04/05) 2Gb DDP (512M x4) * 18 Lead Free & Halogen Free 1066/1333 2 1.5V M392B5273CH0-C(F8/H9)(04/05) 2Gb (256M x8) * 18 Lead Free & Halogen Free 1066/1333 2 1.5V M392B1K73CM0-CF8(H9)(04/05) 2Gb (512M x4) * 18 Lead Free & Halogen Free 1066/1333 1 1.5V 1Gx72 M392B1K73CM0-CF8(H9)(04/05) 4Gb DDP (512M x4) * 18 Lead Free & Halogen Free 1066/1333 2 1.35V 128Mx72 M392B2B73CH0-V(F8/H9)(04/05) 8Gb DDP (2048M x4) * 18 Lead Free & Halogen Free 1066/1333 2 1.35V 128Mx72 M392B5673FH0-Y(F8/H9)(04/05) 1Gb (128M x8) * 9 Lead Free & Halogen Free 1066/1333 1 </td |

NOTES: F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7)

H9 = DDR3-1333 (9-9-9)

04 = IDT B0 register 05 = Inphi C0 register

DDR3 SDRAM UNBUFFERED MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|---------------------------|--------------------|--------------------------|----------------|-------|------------|
| 1GB | 1.5V | 128Mx64 | M378B2873FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.5V | 256Mx64 | M378B5673FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| ZUD | 1.50 | 230IVIX04 | M378B5773FH0-C(F8/H9/K0*) | 2Gb (256M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.5V | 512Mx64 | M378B5273CH0-C(F8/H9/K0*) | 2Gb (256M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.5V | 1024Mx64 | M378B1G73AH0-C(F8/H9/K0*) | 4Gb (512M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |

DDR3 SDRAM UNBUFFERED MODULES (ECC)

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|---------------------------|--------------------|--------------------------|----------------|-------|------------|
| 1GB | 1.5V | 128Mx72 | M391B2873FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.5V | 256Mx72 | M391B5673FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| ZUD | 1.50 | 230IVIX/ 2 | M391B5773FH0-C(F8/H9/K0*) | 2Gb (256M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.5V | 512Mx72 | M391B5273CH0-C(F8/H9/K0*) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.5V | 1024Mx72 | M391B1G73AH0-C(F8/H9/K0*) | 4Gb (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 1GB | 1.35V | 128Mx72 | M391B2873FH0-Y(F8/H9/K0*) | 1Gb (128M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.35V | 256Mx72 | M391B5673FH0-Y(F8/H9/K0*) | 1Gb (128M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| ZUD | 1.337 | 230IVIX/2 | M391B5773FH0-Y(F8/H9/K0*) | 2Gb (256M x8) * 9 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.35V | 512Mx72 | M391B5273CH0-Y(F8/H9/K0*) | 2Gb (256M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.35V | 1024Mx72 | M391B1G73AH0-Y(F8/H9/K0*) | 4Gb (512M x8) * 18 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |

NOTES:

F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7) H9 = DDR3-1333 (9-9-9)

K0 = DDR3-1600 (11-11-11) * K0 (1600Mbps) available in ES only

DDR3 SDRAM SODIMM MODULES

| Density | Voltage | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Ranks | Production |
|---------|---------|--------------|---------------------------|--------------------|--------------------------|----------------|-------|------------|
| 1GB | 1.5V | 128Mx64 | M471B2873FHS-C(F8/H9/K0*) | 1Gb (128M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.5V | 256Mx64 | M471B5673FH0-C(F8/H9/K0*) | 1Gb (128M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| ZUD | 1.50 | 230IVIXU4 | M471B5773FHS-C(F8/H9/K0*) | 2Gb (256M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.5V | 512Mx64 | M471B5273CH0-C(F8/H9/K0*) | 2Gb (256M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.5V | 1024Mx64 | M471B1G73AH0-C(F8/H9/K0*) | 4Gb (512M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 1GB | 1.35V | 128Mx64 | M471B2873FHS-Y(F8/H9/K0*) | 1Gb (128M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 2GB | 1.35V | 256Mx64 | M471B5673FH0-Y(F8/H9/K0*) | 1Gb (128M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 200 | 1.554 | 2J0IVIXU4 | M471B5773FHS-Y(F8/H9/K0*) | 2Gb (256M x8) * 8 | Lead Free & Halogen Free | 1066/1333/1600 | 1 | Now |
| 4GB | 1.35V | 512Mx64 | M471B5273CH0-Y(F8/H9/K0*) | 2Gb (256M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| 8GB | 1.35V | 1024Mx64 | M471B1G73AH0-Y(F8/H9/K0*) | 4Gb (512M x8) * 16 | Lead Free & Halogen Free | 1066/1333/1600 | 2 | Now |
| NOTEO | F= DDD0 | 000 (0.0.0) | (O DDD0 4000 (44 44 44) | | | | | |

NOTES: F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7) K0 = DDR3-1600 (11-11-11) * K0 (1600Mbps) available in ES only

H9 = DDR3-1333 (9-9-9)

DDR3 SDRAM COMPONENTS

| Density | Voltage | Organization | Part Number | # Pins-Package | Compliance | Speed (Mbps) | Dimensions | Production |
|---------|---------|--------------|----------------------------------|----------------|--------------------------|----------------|------------|------------|
| 1Gb | 1.5V | 256M x4 | K4B1G0446F-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| TGD | 1.50 | 128M x8 | K4B1G0846F-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |
| | | 512M x4 | K4B2G0446C-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| 2Gb | 1.5V | 256M x8 | K4B2G0846C-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |
| | | 128M x16 | K4B2G1646C-HC(F8/H9/K0*/MA*/NB*) | 96 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x13.3mm | Now |
| 1Gb | 1.35V | 256M x4 | K4B1G0446F-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| TGD | 1.554 | 128M x8 | K4B1G0846F-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |
| 2Gb | 1.35V | 512M x4 | K4B2G0446C-HC(F8/H9) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333 | 7.5x11mm | Now |
| 200 | 1.557 | 256M x8 | K4B2G0846C-HC(F8/H9/K0*) | 78 Ball -FBGA | Lead Free & Halogen Free | 1066/1333/1600 | 7.5x11mm | Now |

NOTES: F7 = DDR3-800 (6-6-6) F8 = DDR3-1066 (7-7-7) MA = DDR3-1866 (13-13-13) NB = DDR3-2133 (14-14-14)

H9 = DDR3-1333 (9-9-9) * KO, MA, and NB are available in ES only

K0 = DDR3-1600 (11-11-11)

DDR2 SDRAM REGISTERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Register | Rank | Production |
|---------|--------------|-----------------------|--------------|------------|--------------|----------|------|------------|
| 1GB | 128Mx72 | M393T2863FBA-C(E6/F7) | (128M x8)*9 | Lead free | 667/800 | Υ | 1 | Now |
| 2GB | 256Mx72 | M393T5660FBA-C(E6/F7) | (256M x4)*18 | Lead free | 667/800 | Υ | 1 | Now |
| 200 | 230IVIX/ 2 | M393T5663FBA-C(E6/E7) | (128M x8)*18 | Lead free | 667/800 | Υ | 2 | Now |
| 4GB | 512Mx72 | M393T5160FBA-C(E6/F7) | (256M x4)*36 | Lead free | 667/800 | Υ | 2 | Now |

NOTES:

E6=PC2-5300 (DDR2-667 @ CL=5) F7=PC2-6400 (DDR2-800 @ CL=6)

E7=PC2-6400 (DDR2-800 @ CL=5)

Voltage = 1.8V

DDR2 SDRAM VLP REGISTERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Register | Rank | Production |
|---------|--------------|------------------|--------------|------------|--------------|----------|------|------------|
| 2GB | 256Mx72 | M392T5660FBA-CE6 | (256M x4)*18 | | Lead free | 667 | Υ | 1 |

DDR2 SDRAM FULLY BUFFERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Voltage | Rank | Production |
|---------|--------------|-------------------|--------------|------------|--------------|---------|------|------------|
| 2GB | 256Mx72 | M395T5663FB4-CE68 | (128M x8)*18 | Lead free | 667 | 1.8V | 2 | Now |
| 4GB | 512Mx72 | M395T5160FB4-CE68 | (256M x4)*36 | Lead free | 667 | 1.8V | 2 | Now |
| 4UD | 512Mx72 | M395T5163FB4-CE68 | (128M x8)*36 | Lead free | 667 | 1.8V | 4 | Now |

NOTES: E6 = PC2-5300 (DDR2-667 @ CL=5)

AMB = IDT L4

Voltage = 1.8V (AMB Voltage = 1.5V)

DDR2 SDRAM UNBUFFERED MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Rank | Production |
|---------|--------------|--------------------------|--------------|------------|--------------|------|------------|
| 1GB | 128Mx64 | M378T2863FBS-C(E6/F7/E7) | (128M x8)*8 | Lead free | 667/800 | 1 | Now |
| 2GB | 256Mx64 | M378T5663FB3-C(E6/F7/E7) | (128M x8)*16 | Lead free | 667/800 | 2 | Now |

NOTES: E6=PC2-5300 (DDR2-667 @ CL=5)

E7=PC2-6400 (DDR2-800 @ CL=5)

F7=PC2-6400 (DDR2-800 @ CL=6)

Voltage = 1.8V

DDR2 SDRAM UNBUFFERED MODULES (ECC)

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Rank | Production |
|---------|--------------|-----------------------|-------------|------------|--------------|------|------------|
| 1GB | 128Mx72 | M391T2863FB3-C(E6/F7) | (128Mx8)*9 | Lead free | 667/800 | 1 | Now |
| 2GB | 256Mx64 | M391T5663FB3-C(E6/F7) | (128Mx8)*18 | Lead free | 667/800 | 2 | Now |

NOTES:

E6=PC2-5300 (DDR2-667 @ CL=5) E7=PC2-6400 (DDR2-800 @ CL=5)

F7=PC2-6400 (DDR2-800 @ CL=6)

Voltage = 1.8V

DDR2 SDRAM SODIMM MODULES

| Density | Organization | Part Number | Composition | Compliance | Speed (Mbps) | Rank | Production |
|---------|--------------|--------------------------|-------------|------------|--------------|------|------------|
| 1GB | 128Mx64 | M470T2863FB3-C(E6/F7/E7) | (64Mx16)*8 | Lead free | 667/800 | 2 | Now |
| 2GB | 256Mx64 | M470T5663FB3-C(E6/F7/E7) | (128M x8)*8 | Lead free | 667/800 | 2 | Now |

NOTES: E6=PC2-5300 (DDR2-667 @ CL=5)

E7=PC2-6400 (DDR2-800 @ CL=5)

F7=PC2-6400 (DDR2-800 @ CL=6)

Voltage = 1.8V

DDR2 SDRAM COMPONENTS

| Density | Organization | Part Number | # Pins-Package | Dimensions | Package | Speed (Mbps) | Production |
|-----------|--------------|----------------------------|----------------|------------|--------------------------|--------------|------------|
| 256Mb | 16Mx16 | K4T56163QN-HC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| | 128M x4 | K4T51043QI-HC(E6/F7/E7) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800 | Now |
| | 64M x8 | K4T51083QI-HC(E6/F7/E7/F8) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| 512Mb | 32M x16 | K4T51163QI-HC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| O I ZIVID | 128M x4 | K4T51043QJ-HC(E6/F7/E7) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800 | Q3 |
| | 64M x8 | K4T51083QJ-HC(E6/F7/E7/F8) | 60-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800/1066 | Q3 |
| | 32M x16 | K4T51163QJ-HC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Q3 |
| | 256M x4 | K4T1G044QF-BC(E6/F7/E7) | 68-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800 | Now |
| 1Gb | 128M x8 | K4T1G084QF-BC(E6/F7/E7/F8) | 68-FBGA | 7.5x9.5mm | Lead free & Halogen free | 667/800/1066 | Now |
| | 64M x16 | K4T1G164QF-BC(E6/F7/E7/F8) | 84-FBGA | 7.5x12.5mm | Lead free & Halogen free | 667/800/1066 | Now |

NOTES: E6=DDR2-667 (5-5-5)

F7=DDR2-800 (6-6-6)

E7=DDR2-800 (5-5-5)

F8=DDR2-1066 (7-7-7)

Voltage = 1.8V

DDR SDRAM 1U REGISTERED MODULES

| Density | Organization | Part Number | Composition | Speed (Mbps) |
|---------|--|------------------|-------------|--------------|
| 1GB | 128Mx72 | M312L2920GH3-CB3 | (128Mx4)*18 | 333/400 |
| 2GB | 256Mx72 | M312L5720GH3-CB3 | (128Mx4)*36 | 333/400 |
| NOTES: | B0 = DDR266 (133MHz @ CL=2.5) A2 = DDR266 (133MHz @ Cl=2) | | | |

B3 = DDR333 (166MHz @ CL=2.5) CC = DDR400 (200MHz @ CL=3) Type: 184-pin

DDR DRAM SODIMM MODULES

| Density | Organization | Part Number | Composition | Speed (Mbps) |
|---------|--|--------------------|--------------|--------------|
| 512MB | 64Mx64 | M470L6524GL0-CB300 | (32M x 16)*8 | 333 |
| NOTES: | B0 = DDR266 (133MHz @ CL=2.5) CC = DDR400 (200MHz @ CL=3) B3 = DDR333 (166MHz @ CL=2.5) A2 = DDR266 (133MHz @ Cl=2) | | | |

DDR SDRAM COMPONENTS

| Density | Organization | Part Number | # Pins - Package | Speed (Mbps) |
|---------|--------------|--------------------|------------------|--------------|
| | 64Mx4 | K4H560438N-LCB3/B0 | 66-TSOP | 266/333 |
| 256Mb | 32Mx8 | K4H560838N-LCCC/B3 | 66-TSOP | 333/400 |
| | 16Mx16 | K4H561638N-LCCC/B3 | 66-TSOP | 333/400 |
| | 128Mx4 | K4H510438G-LCB3/B0 | 66-TSOP | 266/333 |
| | 1 ZOIVIX4 | K4H510438G-HCCC/B3 | 60-FBGA | 333/400 |
| 512Mb | 64Mx8 | K4H510838G-LCCC/B3 | 66-TSOP | 333/400 |
| | 04IVIXO | K4H510838G-HCCC/B3 | 60-FBGA | 333/400 |
| | 32Mx16 | K4H511638G-LCCC/B3 | 66-TSOP | 333/400 |
| 128Mb | 8Mx16 | K4H2816380-LCCC | 66-TSOP | 400 |

NOTES: B0 = DDR266 (133MHz @ CL=2.5)

A2 = DDR266 (133MHz @ Cl=2)

B3 = DDR333 (166MHz @ CL=2.5) CC = DDR400 (200MHz @ CL=3)

SDRAM COMPONENTS

| Density | Organization | Part Number | # Pins - Package | Speed (Mbps) | Refresh | Remarks |
|---------|--------------|----------------------------|------------------|--------------|---------|-------------------------|
| 64Mb | 8Mx8 | K4S640832N-LC75000 | 54-TSOP | 133 | 4K | EOL with no replacement |
| 04IVID | 4Mx16 | K4S641632N-LC(L)(75/60)000 | 54-TSOP | 133/166 | 4K | EOL with no replacement |
| 100Mh | 16Mx8 | K4S2808320-LC(L)75000 | 54-TSOP | 133 | 4K | |
| | 8Mx16 | K4S2816320-LC(L)(75/60)000 | 54-TSOP | 133/166 | 4K | |
| | 64Mx4 | K4S560432N-LC(L)75000 | 54-TSOP | 133 | 8K | |
| 256Mb | 32Mx8 | K4S560832N-LC(L)75000 | 54-TSOP | 133 | 8K | |
| | 16Mx16 | K4S561632N-LC(L)(75/60)000 | 54-TSOP | 133/166 | 8K | |
| | 128Mx4 | K4S510432D-UC(L)(75)000 | 54-TSOP | 133 | 8K | EOL with no replacement |
| | 64Mx8 | K4S510832D-UC(L)(75)000 | 54-TSOP | 133 | 8K | EOL with no replacement |
| | 32Mx16 | K4S511632D-UC(L)(75)000 | 54-TSOP | 133 | 8K | EOL with no replacement |
| | | | | | | |

NOTES: L = Commercial Temp., Low Power

For Industrial Temperature, check with SSI Marketing

Banks: 4

All products are Lead Free

Voltage: 3.3V

Speed: PC133 (133MHz CL=3/PC100 CL2)

RDRAM COMPONENTS

| Density | Organization | Part Number | Speed (Mbps) | # Pins-Package | Refresh | Note |
|---------|----------------------|--------------------|--------------|----------------|----------|---------------|
| 288M | x18 | K4R881869I-DCT9000 | 1066 | 92-FBGA | 16K/32ms | EOL in Aug'10 |
| NOTES: | All products are lea | ad free | | | ' | |

GRAPHICS DRAM COMPONENTS

| Туре | Density | Organization | Part Number | Package | VDD/VDDQ | Speed Bin (MHz) | Status |
|-------|-------------|--------------|------------------|-----------|------------|-------------------|----------------|
| GDDR5 | 1Gb | 32Mx32 | K4G10325FE-HC(1) | 170-FBGA | 1.5/1.5V | 1800/2000/2500 | |
| | 1Gb | 32Mx32 | K4J10324KE-HC(1) | 136-FBGA | 1.8V/1.8V | 700/800/1000/1200 | |
| GDDR3 | R3 512Mb | 512Mb 16Mx32 | K4J52324QH-HC(1) | 136-FBGA | 1.8/1.8V | 700/800 | EOL Mar '10 |
| כחטטט | | | K4J52324QH-HJ(1) | 136-FBGA | 1.9/1.9V | 1000 | EOL Mar '10 |
| | | | K4J52324QH-HJ(1) | 136-FBGA | 2.05/2.05V | 1200 | EOL Mar '10 |
| GDDR2 | 1Gb | 64Mx16 | K4N1G164QE-HC(1) | 84-FBGA | 1.8/1.8V | 400/500 | EOL Mar '10 |
| UDDNZ | 512Mb | 32Mx16 | K4N51163QG-HC(1) | 84-FBGA | 1.8/1.8V | 400/500 | EOL Mar '10 |
| | GDDR1 128Mb | 4Mx32 | K4D263238K-VC(1) | 144-FBGA | 2.5/2.5V | 200/250 | CuSmpl Oct '09 |
| GDDR1 | | HIVIXOZ | K4D263238K-UC(1) | 100-TQFP | 2.5/2.5V | 200/250 | |
| | | 8Mx16 | K4D261638K-LC(1) | 66-TSOPII | 2.5/2.5V | 200/250 | EOL Sep '10 |

09: 0.90ns (1100MHz)

Package: NOTES:

Q: TQFP

U: TQFP (Lead Free)

G: 84/144 FBGA

V: 144 FBGA (Lead Free) Z: 84 FBGA (Lead Free)

T: TSOP

L: TSOP (Lead Free)

A: 136 FBGA

B: 136 FBGA (Lead Free)

H: FBGA (Halogen Free & Lead Free)

E: 100 FBGA (Halogen Free & Lead Free)

(1) Speeds (clock cycle - speed bin):

04: 0.4ns (2500MHz) 1A: 1ns (1000MHz) 05: 0.5ns (2000MHz) 11: 1.1ns (900MHz) 5C: 0.555 (1800MHz) 12: 1.25ns (800MHz) 14: 1.429ns (700MHz) 33: 3.3ns (300MHz) 07: 0.71ns (1400MHz) 08: 0.83ns (1200MHz)

16: 1.667ns (600MHz) 40: 4.0ns (240MHz) 20: 2.0ns (500MHz)

2A: 2.86ns (350MHz) 50: 5.0ns (200MHz)

22: 2.2ns (450MHz)

25: 2.5ns (400MHz)

MOBILE-SDR/DDR

| Density | Туре | Organization | Part Number | Package | Power | Production |
|-----------|-----------------------|-----------------|------------------|--------------------------|-------|------------|
| | MSDR | 16Mx16 | K4M56163PN-BG(1) | 54-FBGA | 1.8V | Now |
| OEGMb | INIONA | 8Mx32 | K4M56323PN-HG(1) | 90-FBGA | 1.8V | Now |
| 256Mb | MDDD | 16Mx16 | K4X56163PN-FG(1) | 60-FBGA | 1.8V | Now |
| | MSDR 512Mb MDDR | 8Mx32 | K4X56323PN-8G(1) | 90-FBGA | 1.8V | Now |
| | | 32Mx16 | K4M51163PI-BG(1) | 54-FBGA | 1.8V | Now |
| 510Mb | | 16Mx32 | K4M51323PI-HG(1) | 90-FBGA | 1.8V | Now |
| 3 I ZIVID | | 32Mx16 | K4X51163PI-FG(1) | 60-FBGA | 1.8V | Now |
| | MUDK | 16Mx32 | K4X51323PI-8G(1) | 90-FBGA | 1.8V | Now |
| | | 64Mx16 | K4X1G163PE-FG(1) | 60-FBGA | 1.8V | Now |
| 1Gb | MDDR | 32Mx32 | K4X1G323PE-8G(1) | 90-FBGA | 1.8V | Now |
| TGD | IVIDUN | 64Mx16 | K4X1G163PF-FG(1) | 60-FBGA | 1.8V | MP Q1'11 |
| | | 32Mx32 | K4X1G323PF-8G(1) | 90-FBGA | 1.8V | MP Q1'11 |
| 2Gb | MDDD | 128Mx16 | K4X2G163PC-FG(1) | 60-FBGA | 1.8V | Now |
| 200 | MDDR | 64Mx32 | K4X2G323PC-8G(1) | 90-FBGA | 1.8V | Now |
| | | x32 (2CS, 2CKE) | K4X4G303PB-AG(1) | 168-FBGA, 12x12 PoP, DDP | 1.8V | Now |
| 4Gb | MDDR | x32 (2CS, 2CKE) | K4X4G303PB-AG(1) | 168-FBGA, 12x12 PoP, DDP | 1.8V | Now |
| | | x32 (2CS, 2CKE) | K4X4G303PB-7G(1) | 240-FBGA, 14x14 PoP, DDP | 1.8V | Now |

LPDDR2

| Density | Туре | Organization | Part Number | Package | Power | Production |
|---------|--------|--------------|------------------|--------------------------|-------|------------|
| 512Mb | LPDDR2 | 1CH x32 | K4P51323EI-AG(1) | 168-FBGA, 12x12 PoP | 1.8V | Now |
| 1Gb | LPDDR2 | 1CH x32 | K4P1G324EE-AG(1) | 168-FBGA, 12x12 PoP | 1.2V | Now |
| | | 1CH x32 | K4P2G324EC-AG(1) | 168-FBGA, 12x12 PoP | 1.2V | Now |
| 2Gb | LPDDR2 | 2CH x32/ch | K3PE3E300M-XG(1) | 216-FBGA, 12x12 PoP | 1.2V | Now |
| | | | K3PE3E300A-XG(1) | 240-FBGA, 14x14 PoP | 1.2V | Now |
| | | 1CH x32 | K4P4G304EC-AG(1) | 168-FBGA, 12x12 PoP, DDP | 1.2V | Now |
| 4Ch | LPDDR2 | | K3PE4E400M-XG(1) | 216-FBGA, 12x12 PoP, DDP | 1.2V | Now |
| 4Gb | LFUUNZ | 2 2CH x32/ch | K3PE4E400M-XG(1) | 216-FBGA, 12x12 PoP, DDP | 1.2V | Now |
| | | | K3PE4E400A-XG(1) | 240-FBGA, 14x14 PoP, DDP | 1.2V | Now |

NOTES: All products offered at Extended, Low, i-TCSR & PASR & DS (Temp, Power) (1) Speed:

Mobile-SDR 60: 166MHz, CL3

75: 133MHz, CL3

Mobile-DDR

D8: 200MHz, CL3 C6: 166MHz, CL3

LPDDR2

C0: 667Mbps C1: 800Mbps

COMPONENT DRAM ORDERING INFORMATION

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | |
|------------------|---|---|---|----|----|---|---|---|---|----|--------|-------------------|
| | K | 4 | Т | ХХ | XX | X | Х | Х | Х | Х | ХХ | |
| | | | | | | | | | | | | |
| SAMSUNG Memory | | | | | | | | | | | | Speed |
| DRAM | | | | | | | | | | | | Temp & Powe |
| DRAM Type | | | | | | | | | | | | Package Type |
| Density | | | | | | | | | | | | Revision |
| | | | | | | | | | | | Interf | ace (VDD, VDDQ |
| Bit Organization | | | | | | | | | | | Number | of Internal Banks |
| | | | | | | | | | | | | |
| | | | | | | | | | | | | |

1. Memory (K)

2. DRAM: 4

3. DRAM Type

- B: DDR3 SDRAM
- D: GDDR SDRAM
- G: GDDR5 SDRAM
- H: DDR SDRAM
- J: GDDR3 SDRAM
- M: Mobile SDRAM
- N: SDDR2 SDRAM
- S: SDRAM
- T: DDR SDRAM
- U: GDDR4 SDRAM
- V: Mobile DDR SDRAM Power Efficient Address
- W: SDDR3 SDRAM
- X: Mobile DDR SDRAM
- Y: XDR DRAM
- Z: Value Added DRAM

4. Density

- 10: 1G. 8K/32ms
- 16: 16M, 4K/64ms
- 26: 128M, 4K/32ms
- 28: 128M, 4K/64ms
- 32: 32M, 2K/32ms
- 50: 512M, 32K/16ms
- 51: 512M, 8K/64ms
- 52: 512M, 8K/32ms
- 54: 256M, 16K/16ms
- 55: 256M, 4K/32ms
- 56: 256M, 8K/64ms
- 62: 64M, 2K/16ms
- 64: 64M, 4K/64ms
- 68: 768M, 8K/64ms
- 1G: 1G, 8K/64ms
- 2G: 2G, 8K/64ms
- 4G: 4G, 8K/64ms

5. Bit Organization

- 02: x2
- 04: x4
- 06: x4 Stack (Flexframe)
- 07: x8 Stack (Flexframe)

- 08: x8
 - 15: x16 (2CS)
 - 16: x16
- 26: x4 Stack (JEDEC Standard)
- 27: x8 Stack (JEDEC Standard)
- 30: x32 (2CS, 2CKE)
- 31: x32 (2CS)
- 32: x32

6. # of Internal Banks

- 2: 2 Banks
- 3: 4 Banks
- 4: 8 Banks
- 5: 16 Banks

7. Interface (VDD, VDDQ)

- 2: LVTTL, 3.3V, 3.3V
- 4: LVTTL, 2.5V, 2.5V
- 5: SSTL-2 1.8V, 1.8V
- 6: SSTL-15 1.5V, 1.5V
- 8: SSTL-2, 2.5V, 2.5V
- A: SSTL, 2.5V, 1.8V
- F: POD-15 (1.5V,1.5V)
- H: SSTL_2 DLL, 3.3V, 2.5V
- M: LVTTL, 1.8V, 1.5V
- N: LVTTL, 1.5V, 1.5V
- P: LVTTL, 1.8V, 1.8V
- Q: SSTL-2 1.8V, 1.8V
- R: SSTL-2, 2.8V, 2.8V
- U: DRSL, 1.8V, 1.2V

8. Revision

- A: 2nd Generation
- B: 3rd Generation
- C: 4th Generation
- D: 5th Generation
- E: 6th Generation
- - -
- F: 7th Generation
- G: 8th Generation
- H: 9th Generation
- I: 10th Generation
- J: 11th Generation
- K: 12th Generation
- M: 1st Generation
- N: 14th Generation
- Q: 17th Generation

9. Package Type

DDR SDRAM

- L: TSOP II (Lead-free & Halogen-free)
- H: FBGA (Lead-free & Halogen-free)
- F: FBGA for 64Mb DDR (Lead-free & Halogen-free)
- 6: sTSOP II (Lead-free & Halogen-free)
- T: TSOP II
- N: sTSOP II
- G: FBGA
- U: TSOP II (Lead-free)
- V: sTSOP II (Lead-free)
- Z: FBGA (Lead-free)

DDR2 SDRAM

- Z: FBGA (Lead-free)
- J: FBGA DDP (Lead-free)
- Q: FBGA QDP (Lead-free)
- H: FBGA (Lead-free & Halogen-free)
- M: FBGA DDP (Lead-free & Halogen-free)
- E: FBGA QDP (Lead-free & Halogen-free)
- T: FBGA DSP (Lead-free & Halogen-free, Thin)

DDR3 SDRAM

- Z: FBGA (Lead-free)
- H: FBGA (Halogen-free & Lead-free)

Graphics Memory

- Q: TQFP
- U: TQFP (Lead Free)
- G: 84/144 FBGA
- V: 144 FBGA (Lead Free)
- Z: 84 FBGA(Lead Free)
- T: TSOP
- L: TSOP (Lead Free)
- A: 136 FBGA
- B: 136 FBGA(Lead Free)
- H: FBGA(Hologen Free & Lead Free)
- E: 100 FBGA(Hologen Free & Lead Free)

SDRAM

- L TSOP II (Lead-free & Halogen-free)
- N: STSOP II
- T: TSOP II
- U: TSOP II (Lead-free)
- V: sTSOP II (Lead-free)

COMPONENT DRAM ORDERING INFORMATION

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | |
|------------------|---|---|---|----|----|---|---|---|---|----|--------|-----------------|
| | K | 4 | T | XX | XX | X | X | X | Х | X | XX | |
| | | | | | | | | | | | | |
| SAMSUNG Memory | | | | | | | | | | | | Spe |
| DRAM | | | | | | | | | | | | Temp & Pov |
| DRAM Type | | | | | | | | | | | | Package Ty |
| Density | | | | | | | | | | | | Revis |
| Bit Organization | | | | | | | | | | | | face (VDD, VDI |
| Dit Organization | | | | | | | | | | | Number | of Internal Bar |

XDR DRAM

J: BOC(LF) P: BOC

Mobile DRAM

Leaded / Lead Free

G/A: 52balls FBGA Mono

R/B: 54balls FBGA Mono

X /Z: 54balls BOC Mono

J /V: 60(72)balls FBGA Mono 0.5pitch

L /F: 60balls FBGA Mono 0.8pitch

S/D: 90balls FBGA

Monolithic (11mm x 13mm)

F/H: Smaller 90balls FBGA Mono

Y/P: 54balls CSP DDP M/E: 90balls FBGA DDP

10. Temp & Power - COMMON (Temp, Power)

C: Commercial, Normal (0'C - 95'C) & Normal

C: (Mobile Only) Commercial (-25 ~ 70°C), Normal Power

J: Commercial, Medium

L: Commercial, Low (0'C - 95'C) & Low Power

L: (Mobile Only) Commercial, Low, i-TCSR

F: Commercial, Low, i-TCSR & PASR & DS

E: Extended (-25~85'C), Normal

N: Extended, Low, i-TCSR

G: Extended, Low, i-TCSR & PASR & DS

I: Industrial, Normal (-40'C - 85'C) & Normal Power

P: Industrial, Low (-40'C - 85'C) & Low Power

H: Industrial, Low, i-TCSR & PASR & DS

11. Speed (Wafer/Chip Biz/BGD: 00)

DDR SDRAM

CC: DDR400 (200MHz @ CL=3, tRCD=3, tRP=3)

B3: DDR333 (166MHz @ CL=2.5, tRCD=3, tRP=3) *1

A2: DDR266 (133MHz @ CL=2, tRCD=3, tRP=3)

B0: DDR266 (133MHz @ CL=2.5, tRCD=3, tRP=3)

Note 1: "B3" has compatibility with "A2" and "B0"

DDR2 SDRAM

CC: DDR2-400 (200MHz @ CL=3, tRCD=3,

D5: DDR2-533 (266MHz @ CL=4, tRCD=4, tRP=4

E6: DDR2-667 (333MHz @ CL=5, tRCD=5, tRP=5)

F7: DDR2-800 (400MHz @ CL=6, tRCD=6,

E7: DDR2-800 (400MHz @ CL=5, tRCD=5, tRP=5)

DDR3 SDRAM

F7: DDR3-800 (400MHz @ CL=6, tRCD=6, tRP=6)

F8: DDR3-1066 (533MHz @ CL=7, tRCD=7,

G8: DDR3-1066 (533MHz @ CL=8, tRCD=8, tRP=8)

H9: DDR3-1333 (667MHz @ CL=9, tRCD=9,

KO: DDR3-1600 (800MHz @ CL=11, tRCD=11, tRP=11)

Graphics Memory

18: 1.8ns (550MHz)

04: 0.4ns (2500MHz)

20: 2.0ns (500MHz)

05: 0.5ns (2000MHz)

22: 2.2ns (450MHz)

5C: 0.56ns (1800MHz)

25: 2.5ns (400MHz)

06: 0.62ns (1600MHz)

2C: 2.66ns (375MHz)

6A: 0.66ns (1500MHz)

2A: 2.86ns (350MHz)

07: 0.71ns (1400MHz)

33: 3.3ns (300MHz)

7A: 0.77ns (1300MHz)

36: 3.6ns (275MHz)

08: 0.8ns (1200MHz)

40: 4.0ns (250MHz)

09: 0.9ns (1100MHz)

45: 4.5ns (222MHz)

1:1.0ns (1000MHz)

50/5A: 5.0ns (200MHz)

1:1.1ns (900MHz)

55: 5.5ns (183MHz)

12: 1.25ns (800MHz)

60: 6.0ns (166MHz)

14: 1.4ns (700MHz)

16: 1.6ns (600MHz)

SDRAM (Default CL=3)

50: 5.0ns (200MHz CL=3)

60: 6.0ns (166MHz CL=3)

67: 6.7ns

75: 7.5ns PC133 (133MHz CL=3)

XDR DRAM

A2: 2.4Gbps, 36ns, 16Cycles

B3: 3.2Gbps, 35ns, 20Cycles

C3: 3.2Gbps, 35ns, 24Cycles

C4: 4.0Gbps, 28ns, 24Cycles

DS: Daisychain Sample

Mobile-SDRAM

60: 166MHz. CL 3

75: 133MHz, CL 3

80: 125MHz, CL 3

1H: 105MHz, CL 2

1L: 105MHz, CL 3

15: 66MHz, CL 2 & 3

Mobile-DDR

C3: 133MHz, CL 3

C2: 100MHz, CL 3

C0: 66MHz, CL 3

Note: All of Lead-free or Halogen-free product are in compliance with RoHS

MODULE DRAM ORDERING INFORMATION

| 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | |
|---------------------|---|----|---|----|---|---|---|---|----|----|----|-----|------------------|
| M | Х | XX | T | XX | Х | X | X | X | Х | X | XX | Х | |
| SAMSUNG Memory | | | | | | | | | | | | | AMB Vendor |
| DIMM | | | | | | | | | | | | | Speed |
| Data bits | | | | | | | | | | | | | |
| DRAM Component Type | | | | | | | | | | | | | PCB Revision |
| Depth | | | | | | | | | | | | | Package |
| Number of Banks | | | | | | | | | | | | Cor | mponent Revision |
| Bit Organization | | | | | | | | | | | | | |

1. Memory Module: M

2. DIMM Type

- 3: DIMM
- 4: SODIMM

3. Data bits

- 12: x72 184pin Low Profile Registered DIMM
- 63: x63 PC100 / PC133 μ SODIMM with SPD for 144pin
- 64: x64 PC100 / PC133 SODIMM with SPD for 144pin (Intel/JEDEC)
- 66: x64 Unbuffered DIMM with SPD for 144pin/168pin (Intel/JEDEC)
- 68: x64 184pin Unbuffered DIMM
- 70: x64 200pin Unbuffered SODIMM
- 71: x64 204pin Unbuffered SODIMM
- 74: x72 /ECC Unbuffered DIMM with SPD for 168pin (Intel/JEDEC)
- 77: x72 /ECC PLL + Register DIMM with SPD for 168pin (Intel PC100)
- 78: x64 240pin Unbuffered DIMM
- 81: x72 184pin ECC unbuffered DIMM
- 83: x72 184pin Registered DIMM
- 90: x72 /ECC PLL + Register DIMM
- 91: x72 240pin ECC unbuffered DIMM
- 92: x72 240pin VLP Registered DIMM
- 93: x72 240pin Registered DIMM
- 95: x72 240pin Fully Buffered DIMM with SPD for 168pin (JEDEC PC133)

4. DRAM Component Type

- B: DDR3 SDRAM (1.5V VDD)
- L: DDR SDRAM (2.5V VDD)
- S: SDRAM
- T: DDR2 SDRAM (1.8V VDD)

5. Depth

- 09: 8M (for 128Mb/512Mb)
- 17: 16M (for 128Mb/512Mb)
- 16: 16M
- 28: 128M
- 29: 128M (for 128Mb/512Mb)
- 32: 32M
- 33: 32M (for 128Mb/512Mb)
- 51: 512M
- 52: 512M (for 512Mb/2Gb)
- 56: 256M
- 57: 256M (for 512Mb/2Gb)
- 59: 256M (for 128Mb/512Mb)
- 64: 64M
- 65: 64M (for 128Mb/512Mb)
- 1G: 1G
- 1K: 1G (for 2Gb)

6. # of Banks in Comp. & Interface

- 1: 4K/64mxRef., 4Banks & SSTL-2
- 2:8K/64ms Ref., 4Banks & SSTL-2
- 2: 4K/ 64ms Ref., 4Banks & LVTTL (SDR Only)
- 5: 8K/ 64ms Ref., 4Banks & LVTTL (SDR Only)
- 5: 4Banks & SSTL-1.8V
- 6: 8Banks & SSTL-1.8V

7. Bit Organization

- 0: x 4
- 3: x 8
- 4: x16
- 6: x 4 Stack (JEDEC Standard)
- 7: x 8 Stack (JEDEC Standard)
- 8: x 4 Stack
- 9: x 8 Stack

8. Component Revision

- A: 2nd Gen.
- B: 3rd Gen.
- C: 4th Gen.
- D: 5th Gen.
- E: 6th Gen.
- L. Our don.
- F: 7th Gen.
- G: 8th Gen.
- M: 1st Gen.
- Q: 17th Gen.

9. Package

- E: FBGA QDP (Lead-free & Halogen-free)
- G: FBGA
- H: FBGA (Lead-free & Halogen-free)
- J: FBGA DDP (Lead-free)
- M: FBGA DDP (Lead-free & Halogen-free)
- N: sTSOP
- Q: FBGA QDP (Lead-free)
- T: TSOP II (400mil)
- U: TSOP II (Lead-Free)
- V: sTSOP II (Lead-Free)
- Z: FBGA(Lead-free)

10. PCB Revision

- 0: Mother PCB
- 1: 1st Rev
- 2: 2nd Rev.
- 3: 3rd Rev.
- 4: 4th Rev.
- A: Parity DIMM
- S: Reduced PCB
- U: Low Profile DIMM

11. Temp & Power

- C: Commercial Temp. (0°C ~ 95°C) & Normal
- L: Commercial Temp. (0°C ~ 95°C) & Low Power

12. Speed

- CC: (200MHz @ CL=3, tRCD=3, tRP=3)
- D5: (266MHz @ CL=4, tRCD=4, tRP=4)
- E6: (333MHz @ CL=5, tRCD=5, tRP=5)
- F7: (400MHz @ CL=6, tRCD=6, tRP=6)
- E7: (400MHz @ CL=5, tRCD=5, tRP=5)
- F8: (533MHz @ CL=7, tRCD=7, tRP=7)
- G8: (533MHz @ CL=8, tRCD=8, tRP=8)
- H9: (667MHz @ CL=9, tRCD=9, tRP=9)
- K0: (800MHz @ CL=10, tRCD=10, tRP=10)
- 10. (00011112 @ 0L=10, 1110D=10, 1111 = 10)
- 7A: (133MHz CL=3/PC100 CL2)

13. AMB Vendor for FBDIMM

- 0, 5: Intel
- 1, 6, 8: IDT
- 9: Montage
- Note: All of Lead-free or Halogen-free product are in compliance with RoHS

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SLC FLASH

| | | | | | | | MOQ | | |
|-----------|------------|-----------------|-----------------|------|--------|----------|----------|--------|--|
| amily | Density | Part Number | Package Type | Org. | Vol(V) | Tray | T/R | Status | |
| | | | | | | -xxxx0xx | -xxx0Txx | 7.0 | |
| | 16Gb Mono | K9FAG08U0M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S | |
| | | K9FAG08S0M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S | |
| | 32Gb DDP | K9KBG08U1M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S | |
| Gb Based | | K9KBG08S1M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S | |
| | 64Gb QDP | K9WCG08U5M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S | |
| | | K9WCG08S5M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S | |
| | 128Gb ODP | K9QDG08U5M-HCB0 | BGA | X8 | 3.3 | 960 | 1000 | E/S | |
| | | K9QDG08S5M-HCB0 | BGA | X8 | 1.8 | 960 | 1000 | E/S | |
| | 64Gb DSP | K9NCG08U5M-PCK0 | TS0P1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | 32Gb QDP | K9WBG08U1M-PCB0 | TS0P1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9WBG08U1M-PIB0 | TS0P1 | х8 | 3.3 | 960 | 1000 | M/P | |
| b Based | 16Gb DDP | K9KAG08U0M-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9KAG08U0M-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | 8Gb Mono | K9F8G08U0M-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F8G08U0M-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9WAG08U1D-SCB0 | TSOP1 HF&LF | х8 | 3.3 | 960 | 1000 | C/S | |
| | | K9WAG08U1D-SIB0 | TSOP1 HF&LF | х8 | 3.3 | 960 | 1000 | C/S | |
| | 16Gb QDP | K9WAG08U1B-PCB0 | TS0P1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9WAG08U1B-PIB0 | TS0P1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9WAG08U1B-KIB0 | ULGA HF & LF | х8 | 3.3 | 960 | 2000 | M/P | |
| | | K9K8G08U0D-SCB0 | TSOP1 HF&LF | X8 | 3.3 | 960 | 1000 | C/S | |
| | | K9K8G08U0D-SIB0 | TSOP1 HF&LF | x8 | 3.3 | 960 | 1000 | C/S | |
| ab Based | 8Gb DDP | K9K8G08U0B-PCB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P | |
| | | K9K8G08U0B-PIB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P | |
| | | K9K8G08U1B-KIB0 | ULGA HF & LF | х8 | 3.3 | 960 | 2000 | M/P | |
| | | K9F4G08U0D-SCB0 | TSOP1 HF & LF | x8 | 3.3 | 960 | 1000 | C/S | |
| | | K9F4G08U0D-SIB0 | TSOP1 HF& LF | X8 | 3.3 | 960 | 1000 | C/S | |
| | 4Gb Mono | K9F4G08U0B-PCB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F4G08U0B-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F4G08U0B-KIB0 | ULGA HF & LF | x8 | 3.3 | 960 | 2000 | M/P | |
| | | K9F2G08U0C-SCB0 | TSOP-LF/HF | x8 | 3.3 | 960 | 1000 | C/S | |
| h Donas | OCh Man- | K9F2G08U0C-SIB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S | |
| ab Based | 2Gb Mono | K9F2G08U0B-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F2G08U0B-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F1G08U0D-SCB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S | |
| N- D I | 10-14 | K9F1G08U0D-SIB0 | TSOP-LF/HF | х8 | 3.3 | 960 | 1000 | C/S | |
| b Based | 1Gb Mono | K9F1G08U0C-PCB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F1G08U0C-PIB0 | TSOP1 | x8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F1208U0C-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | 5 (O M) | K9F1208U0C-PIB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| 2Mb Based | 512Mb Mono | K9F1208R0C-JIB0 | 63 FBGA(8.5x13) | х8 | 1.8 | 1120 | - | M/P | |
| | | K9F1208U0C-JIB0 | 63 FBGA(8.5x13) | х8 | 3.3 | 1120 | - | M/P | |
| | | K9F5608U0D-PCB0 | TSOP1 | х8 | 3.3 | 960 | 1000 | M/P | |
| | | K9F5608U0D-PIB0 | TSOP1 | х8 | 3.3 | 1000 | 1000 | M/P | |
| 6Mb Based | 256Mb Mono | K9F5608R0D-JIB0 | 63 FBGA(9x11) | х8 | 1.8 | 1280 | 2000 | M/P | |
| | | K9F5608U0D-JIB0 | 63 FBGA(9x11) | х8 | 3.3 | 1280 | 2000 | M/P | |

 $\label{lem:please contact your local Samsung sales representative for latest product offerings.$

Note: All parts are lead free

MLC FLASH

| | | | | | | | | M | 0Q | |
|------|------------|-----------|------------|--------------------|---------------------------------|------|--------|-----------|----------|----------------------|
| Туре | Family | Density | Technology | Part Number | Package Type | Org. | Vol(V) | Tray | T/R | Comments |
| | | | | | .,,,,, | | | -ххххх0хх | -xxx0Txx | |
| | | 32Gb Mono | 27nm | K9HDG08U1A-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | 32Gb Based | 64Gb DDP | 27nm | K9LCG08U0A-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | | 128Gb QDP | 27nm | K9GBG08U0A-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| 2bit | | 16Gb Mono | 32nm | K9GAG08U0E-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | 16Gb Based | 32Gb DDP | 32nm | K9LBG08U0E-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | | 64Gb QDP | 32nm | K9HCG08U1E-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | 8Gb Based | 8Gb Mono | 32nm | K9G8G08U0C-SCB0 | TSOP - Lead free & Halogen free | х8 | 3.3 | 960 | 1000 | |
| | | 32Gb mono | 32nm | K9CDG08U5A-MCB0001 | LGA - Lead free & Halogen free | x8 | 3.3 | 840 | - | Moving to 2xnm Q3'10 |
| 3bit | 32Gb Based | 64Gb DDP | 32nm | K9BCG08U1A-MCB0001 | LGA - Lead free & Halogen free | х8 | 3.3 | 840 | - | Moving to 2xnm Q3'10 |
| | | 128Gb QDP | 32nm | K9ABG08U0A-MCB0001 | LGA - Lead free & Halogen free | х8 | 3.3 | 840 | - | Moving to 2xnm Q3'10 |

Please contact your local Samsung sales representative for latest product offerings. Note: All parts are lead free

SD and MicroSD FLASH CARDS

| Application | Density | Controller | | | | | | |
|--------------|---------|--|--|--|--|--|--|--|
| | 2GB | | | | | | | |
| CD Coud | 4GB | | | | | | | |
| SD Card | 8GB | Contact your local Samsung rep for availability and ordering information | | | | | | |
| | 16GB | | | | | | | |
| 2 | 2GB | | | | | | | |
| | 4GB | | | | | | | |
| MicroSD Card | 8GB | Contact your local Samsung rep for availability and ordering information | | | | | | |
| | 16GB | | | | | | | |
| | 32GB | | | | | | | |

Please contact your local Samsung sales representative for latest product offerings. Note: All parts are lead free

SOLID STATE DRIVES (SSD)

| COLID CITT | | , _ (000) | | | | |
|--------------------|-------|-----------|------------------|---------------------------|----------|--------------------|
| Interface | Size | Connector | Controller | Comp. | Capacity | Part Number |
| | | | | | 64GB | MZ5PA064HMCD-0A000 |
| CATA II (Nighting) | 0.5" | Thin CATA | MAX | 16Gb | 128GB | MZ5PA128HMCD-0A000 |
| SATA II (Native) | 2.5" | Thin SATA | | | 256GB | MZ5PA256HMDR-0A000 |
| | | | TMDDR Controller | 32Gb Toggle-Mode DDR NAND | 512GB | Contact Sales |
| | | | | | 32GB | MZMPA032HMCD-00000 |
| SATA II (Native) | mSATA | mSATA | MAX | 16Gb | 64GB | MZMPA064HMDR-00000 |
| | | | | | 128GB | MZMPA128HMFU-00000 |

Please contact your local Samsung sales representative for latest product offerings.

Note: All parts are lead free

FLASH PRODUCT ORDERING INFORMATION



NtRAM

| Туре | Density | Organization | Part Number | Package | Operating Mode | Vdd (V) | Access Time tCD (ns) | Speed tCYC (MHz) | I/O Voltage (V) | Production Status |
|------------|---------|--------------|----------------|-------------------|-------------------|------------|-------------------------|---------------------|--------------------|----------------------|
| | 72Mb | 2Mx36 | K7N643645M | 100-TQFP, 165FBGA | SPB | 2.5 | 2.6, 3.5 | 250, 167 | 2.5 | Mass Production |
| | / ZIVID | 4Mx18 | K7N641845M | 100-TQFP, 165FBGA | SPB | 2.5 | 2.6, 3.5 | 250, 167 | 2.5 | Mass Production |
| | | 1Mx36 | K7N323635C | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | 36Mb | 2Mx18 | K7N321835C | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | SOIVID | 1Mx36 | K7M323635C | 100-TQFP | FT | 3.3, 2.5 | 7.5 | 118 | 3.3, 2.5 | Mass Production |
| | | 2Mx18 | K7M321835C | 100-TQFP | FT | 3.3, 2.5 | 7.5 | 118 | 3.3, 2.5 | Mass Production |
| | | 1Mx18 | K7N161831B | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | 18Mb | 512Kx36 | K7N163631B | 100-TQFP, 165FBGA | SPB | 3.3, 2.5 | 2.6, 3.5 | 250, 167 | 3.3, 2.5 | Mass Production |
| | IOIVID | 1Mx18 | K7M161835B | 100-TQFP | FT (SB) | 3.3 | 6.5 | 133 | 3.3, 2.5 | Mass Production |
| | | 512Kx36 | K7M163635B | 100-TQFP | FT (SB) | 3.3 | 6.5 | 133 | 3.3, 2.5 | Mass Production |
| NtRAM | | 256Kx36 | K7N803601B | 100-TQFP | SPB | 3.3 | 3.5 | 167 | 3.3,2.5 | Not for new designs |
| INIMAINI | | 512Kx18 | K7N801801B | 100-TQFP | SPB | 3.3 | 3.5 | 167 | 3.3,2.5 | Not for new designs |
| | | 256Kx36 | K7N803609B | 100-TQFP | SPB | 3.3 | 2.6 | 250 | 3.3,2.5 | Not for new designs |
| | | 512Kx18 | K7N801809B | 100-TQFP | SPB | 3.3 | 2.6 | 250 | 3.3,2.5 | Not for new designs |
| | 8Mb | 256Kx36 | K7N803645B | 100-TQFP | SPB | 2.5 | 3.5 | 167 | 2.5 | Not for new designs |
| | OIVID | 512Kx18 | K7N801845B | 100-TQFP | SPB | 2.5 | 3.5 | 167 | 2.5 | Not for new designs |
| | | 256Kx36 | K7N803649B | 100-TQFP | SPB | 2.5 | 2.6 | 250 | 2.5 | Not for new designs |
| | | 512Kx18 | K7N801849B | 100-TQFP | SPB | 2.5 | 2.6 | 250 | 2.5 | Not for new designs |
| | | 512Kx18 | K7M801825B | 100-TQFP | FT | 3.3 | 6.5 | 133 | 3.3, 2.5 | Not for new designs |
| | | 256Kx36 | K7M803625B | 100-TQFP | FT | 3.3 | 6.5 | 133 | 3.3, 2.5 | Not for new designs |
| | 4Mb | 128Kx36 | K7N403609B | 100-TQFP | SPB | 3.3 | 3 | 200 | 3.3,2.5 | Not for new designs |
| | 4Mb | 256Kx18 | K7N401809B | 100-TQFP | SPB | 3.3 | 3 | 200 | 3.3,2.5 | Not for new designs |
| SPB and FT | 4Mb | 256Kx18 | K7B401825B | 100-TQFP | SB | 3.3 | 6.5 | 133 | 3.3, 2.5 | Not for new designs |

NOTES:

All TQFP products are lead free NtRAM speed recommendations: For 200MHz use 250MHz; For 133MHz use 167MHz NtRAM speed recommendation: Use 7.5ns Access Time use 6.5ns Access Time Recommended SPB speeds are 250MHz and 167MHz Recommended SPB Acess Speed is 7.5ns

Late-Write RR SRAM

| Density | Organization | Part Number | Package | Operating Mode | Vdd (V) | Access Time tCD (ns) | Speed tCYC (MHz) | I/O Voltage (V) | Production Status |
|---------|--------------|-------------|---------|-------------------|------------|-------------------------|---------------------|-----------------|-------------------|
| 32Mb | 1Mx36 | K7P323674C | 119-BGA | SP | 1.8 / 2.5V | 1.6, 2.0 | 300,250 | 1.5 (Max 1.8) | Mass Production |
| 32IVID | 2Mx18 | K7P321874C | 119-BGA | SP | 1.8 / 2.5V | 1.6, 2.0 | 300,250 | 1.5 (Max 1.8) | Mass Production |
| | 256Kx36 | K7P803611B | 119-BGA | SP | 3.3 | 1.6 | 300 | 1.5 (Max.2.0) | Mass Production |
| OMb | 512Kx18 | K7P801811B | 119-BGA | SP | 3.3 | 1.6 | 300 | 1.5 (Max.2.0) | Mass Production |
| 8Mb | 256Kx36 | K7P803666B | 119-BGA | SP | 2.5 | 2 | 250 | 1.5 (Max.2.0) | Mass Production |
| | 512Kx18 | K7P801866B | 119-BGA | SP | 2.5 | 2 | 250 | 1.5 (Max.2.0) | Mass Production |

DDR SYNCHRONOUS SRAM

| Туре | Density | Organization | Part Number | Package | Vdd (V) | Access Time tCD (ns) | Cycle Time (MHz) | I/O Voltage (V) | Production Status | Comments |
|----------------|---------|--------------|----------------|----------|------------|-------------------------|---------------------|--------------------|----------------------|---------------------------------------|
| | 16Mb | 512Kx36 | K7D163674B | 153-BGA | 1.8~2.5 | 2.3 | 330, 300 | 1.5~1.9 | Mass Production | |
| DDR | 16Mb | 1Mx18 | K7D161874B | 153-BGA | 1.8~2.5 | 2.3 | 330, 300 | 1.5~1.9 | Mass Production | |
| חטט | 8Mb | 256Kx36 | K7D803671B | 153-BGA | 2.5 | 1.7/1.9/2.1 | 333, 330, 250 | 1.5 (Max 2.0) | Not for new designs | |
| | OIVID | 512Kx18 | K7D801871B | 153-BGA | 2.5 | 1.7/1.9/2.1 | 333, 330, 250 | 1.5 (Max 2.0) | Not for new designs | |
| | | | K7l641882M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 4Mx18 | K7I641884M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | 70Mb | | K7J641882M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | 72Mb | | K7l643682M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 2Mx36 | K7I643684M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | | | K7J643682M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | | | K7l321882C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 2Mx18 | K7I321884C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-4B |
| DDR | OCMb | | K7J321882C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | SIO-2B |
| II CIO/ SIO | 36Mb | | K7I323682C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 1Mx36 | K7I323684C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | CIO-4B |
| | | | K7J323682C | 165-FBGA | 1.8 | 0.45 | 300,250 | 1.5,1.8 | Mass Production | SIO-2B |
| | | | K7I161882B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | 1Mx18 | K7I161884B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | 10Mb | | K7J161882B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | 18Mb | | K7J163682B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | SIO-2B |
| | | 512Kx36 | K7I163682B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-2B |
| | | | K7I163684B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | CIO-4B |
| | | 014.40 | K7K3218T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| | OCM In | 2Mx18 | K7K3218U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |
| | 36Mb | 1111/26 | K7K3236T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| DDR II+ | | 1Mx36 | K7K3236U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |
| CIO | | 1111-10 | K7K1618T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| | 40046 | 1Mx18 | K7K1618U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |
| | 18Mb | E10Kv00 | K7K1636T2C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | DDRII + CIO-2B, 2 clocks latancy |
| | | 512Kx36 | K7K1636U2C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | DDRII + CIO-2B, 2.5 clocks latancy |

NOTES:

2B = Burst of 2 4B = Burst of 4

SIO = Separate I/O

For DDR II CIO/SIO: C-die use 330, 300, or 250MHz instad of 200MHz or 167MHz using a stable DLL circuit For DDR II+ CIO: 2-clock latency is available. A 2.5-clock latency can be supported on 18Mb at 500Mhz and 36Mb at 450MHz

ODR SYNCHRONOUS SRAM

| Туре | Density | Organization | Part Number | Package | Vdd (V) | Access Time tCD (ns) | Cycle Time | I/O Voltage (V) | Production Status | Comments |
|---------|--------------|--------------|----------------|----------|-------------|-------------------------|-----------------|--------------------|----------------------|---------------------------------------|
| | | 414-40 | K7Q161862B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 2B |
| ODDI | 10116 | 1Mx18 | K7Q161864B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 4B |
| QDR I | 18Mb | E101/v26 | K7Q163662B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 2B |
| | | 512Kx36 | K7Q163664B | 165-FBGA | 1.8v / 2.5v | 2.5 | 167 | 1.5,1.8 | Mass Production | QDR I - 4B |
| | | 8Mx9 | K7R640982M | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | 484.40 | K7R641882M | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II-2B |
| | 72Mb | 4Mx18 | K7R641884M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 2Mx36 | K7R643682M | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | ZIVIX30 | K7R643684M | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 4Mx9 | K7R320982C | 165-FBGA | 1.8 | 0.45 | 167, 250, 200 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | 014.40 | K7R321882C | 165-FBGA | 1.8 | 0.45 | 167, 250, 200 | 1.5,1.8 | Mass Production | QDR II-2B |
| QDR II | 36Mb | 2Mx18 | K7R321884C | 165-FBGA | 1.8 | 0.45 | 200, 300, 250 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 1111100 | K7R323682C | 165-FBGA | 1.8 | 0.45 | 300, 250, 200 | 1.5,1.8 | Mass Production | QDR II-2B |
| | | 1Mx36 | K7R323684C | 165-FBGA | 1.8 | 0.45 | 200, 300, 250 | 1.5,1.8 | Mass Production | QDR II-4B |
| | | 2Mx9 | K7R160982B | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II - 2B |
| | | 414.40 | K7R161882B | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II - 2B |
| | 18Mb | 1Mx18 | K7R161884B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II - 4B |
| | | E101/v26 | K7R163682B | 165-FBGA | 1.8 | 0.45,0.45,0.50 | 250,200,167 | 1.5,1.8 | Mass Production | QDR II - 2B |
| | | 512Kx36 | K7R163684B | 165-FBGA | 1.8 | 0.45,0.45,0.45,0.50 | 300,250,200,167 | 1.5,1.8 | Mass Production | QDR II - 4B |
| | | 414.00 | K7S3236T4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2 clocks latancy |
| | 0014 | 1Mx36 | K7S3236U4C | 165-FBGA | 1.8 | 0.45 | 400, 334 | 2.5 | Mass Production | QDR II + 4B, 2.5 clocks latancy |
| 0DD II | 36Mb | 01440 | K7S3218T4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2 clocks latancy |
| QDR II+ | | 2Mx18 | K7S3218U4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2.5 clocks latancy |
| | 101/16 | 1Mx18 | K7S1618T4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2 clocks latancy |
| | 18Mb 512Kx36 | | K7S1636U4C | 165-FBGA | 1.8 | 0.45 | 400, 333 | 1.5 | Mass Production | QDR II + 4B, 2.5 clocks latancy |

NOTES:

For QDR I, QDR II: 2B = Burst of 2, 4B = Burst of 4
For QDR II (36Mb): C-die use 300, 250MHz or 200MHz instead of 167MHz using a stable DLL circuit
For QDR II (72Mb): 2B = Burst of 2 and 250MHz or 200MHz is recommended, 4B = Burst of 4 and 300MHz or 250MHz is recommended
For QDR II+: 2-clock latency supported. 2.5-clock latency can be supported with 450MHz speed

SYNCHRONOUS SRAM ORDERING INFORMATION

| 9 10 11 12 13 14 15 16 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 |
|------------------------|----|----|----|----|---|---|---|---|---|---|---|---|-------------------|
| X X - X X X X X | Х | X | - | X | X | Х | X | X | X | X | X | 7 | K |
| Packaging Ty | | | | | | | | | | | | | SUNG Memory |
| Spec | | | | | | | | | | | | | SRAM |
| Spec | | | | | | | | | | | | | II Classification |
| Temp, Pow | | | | | | | | | | | | | sity |
| Packag | | | | | | | | | | | | | sity |
| | | | | | | | | | | | | | nization |
| Generation | | | | | | | | | | | | | nization |
| Vcc, Interface, Mod | | | | | | | | | | | | | Interface, Mode |

1. Memory (K)

2. Sync SRAM: 7

3. Small Classification

- A: Sync Pipelined Burst
 - B: Sync Burst
 - D: Double Data Rate
 - I: Double Data Rate II, Common I/O
- J: Double Data Rate, Separate I/O
- K: Double Data II+, Common I/O
- M: Sync Burst + NtRAM
- N: Sync Pipelined Burst + NtRAM
- P: Sync Pipe
- Q: Quad Data Rate I
- R: Quad Data Rate II
- S: Quad Data Rate II+

4~5. Density

| 80: 8M | 16: 18M |
|---------|---------|
| 40: 4M | 32: 36M |
| 64: 72M | |

6~7. Organization

| 08: x8 | 09: x9 |
|---------|---------|
| 18: x18 | 32: x32 |
| 36: x36 | |

8~9. Vcc, Interface, Mode

- 00: 3.3V,LVTTL,2E1D WIDE
- 01: 3.3V,LVTTL,2E2D WIDE
- 08: 3.3V,LVTTL,2E2D Hi SPEED
- 09: 3.3V,LVTTL,Hi SPEED
- 11: 3.3V,HSTL,R-R
- 12: 3.3V,HSTL,R-L
- 14: 3.3V,HSTL,R-R Fixed ZQ
- 22: 3.3V,LVTTL,R-R
- 23: 3.3V,LVTTL,R-L
- 25: 3.3V,LVTTL,SB-FT WIDE
- 30: 1.8/2.5/3.3V,LVTTL,2E1D
- 31: 1.8/2.5/3.3V,LVTTL,2E2D
- 35: 1.8/2.5/3.3V,LVTTL,SB-FT
- 44: 2.5V,LVTTL,2E1D

20

45: 2.5V,LVTTL,2E2D

- 49: 2.5V,LVTTL,Hi SPEED
- 52: 2.5V,1.5/1.8V,HSTL,Burst2
- 54: 2.5V,1.5/1.8V,HSTL,Burst4
- 62: 2.5V/1.8V,HSTL,Burst2
- 64: 2.5V/1.8V,HSTL,Burst4
- 66: 2.5V,HSTL,R-R
- 74: 1.8V,2.5V,HSTL,AII
- 82: 1.8V,HSTL,Burst2
- 84: 1.8V, HSTL, Burst4
- 88: 1.8V,HSTL,R-R
- T2: 1.8V,2Clock Latency,Burst2
- T4: 1.8V,2Clock Latency,Burst4
- U2: 1.8V,2.5Clock Latency, Burst2
- U4: 1.8V,2.5Clock Latency, Burst4

10. Generation

- M: 1st Generation
- A: 2nd Generation
- B: 3rd Generation
- C: 4th Generation
- D: 5th Generation

11. "--"

12. Package

- H: BGA.FCBGA.PBGA
- G: BGA, FCBGA, FBGA (LF)
- F: FBGA
- E: FBGA (LF)
- Q: (L)QPF
- P: (L)QFP(LF)
- C: CHIP BIZ
- W: WAFER

13. Temp, Power

COMMON (Temp,Power)

- 0: NONE, NONE (Containing of error
- handling code)
- C: Commercial, Normal
- E: Extended, Normal
- I: Industrial, Normal

WAFER, CHIP BIZ Level Division

- 0: NONE, NONE
- 1: Hot DC sort
- 2: Hot DC, selected AC sort

14~15. Speed

Sync Burst,Sync Burst + NtRAM

- < Mode is R-L > (Clock Accesss Time) 65: 6.5ns 70: 7ns
- 75: 7.5ns 80: 8ns
- 85: 8.5ns

Other Small Classification (Clock Cycle Time)

- 10: 100MHz
 11: 117MHz

 13: 133MHz
 14: 138MHz

 16: 166MHz
 20: 200MHz

 25: 250MHz
 27: 275MHz
- 30: 300MHz 33: 333MHz 35: 350MHz 37: 375MHz
- 40: 400MHz(t-CYCLE) 42: 425MHz
- 45: 450MHz 50: 500MHz (except Sync Pipe)

16. Packing Type (16 digit)

- Common to all products, except of Mask ROM
- Divided into TAPE & REEL (In Mask ROM, divided into TRAY, AMMO packing separately)

| Туре | Packing Type | New Marking |
|------------|-------------------------|--------------------|
| Component | TAPE & REEL | T |
| | Other (Tray, Tube, Jar) | 0 (Number) |
| | Stack | S |
| Component | TRAY | Υ |
| (Mask ROM) | AMMO PACKING | A |
| Module | MODULE TAPE & REEL | Р |
| | MODULE Other Packing | М |
| | | |

MCP: NAND/DRAM

| Memory | NAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|-------------|--------------|---------------------|----------------------|-------------|-----------------|
| | | 256Mb (x16,x32) | 3.0V/1.8V - 1.8V | 107/137FBGA | 152FBGA |
| | 1Gb | 512Mb (x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | 119/152FBGA |
| NAND & DRAM | | 1Gb (x32) | 1.8V - 1.8V | 137FBGA | - |
| NAND & DRAW | 2Ch | 512Mb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | 119/152FBGA |
| | 2Gb | 1Gb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | 152/160/168FBGA |
| | 4Gb | 1Gb (x32) | 2.7V - 1.8V | 137FBGA | - |

MCP: OneNAND/DRAM

| Memory | OneNAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|----------------|-----------------|---------------------|----------------------|-------------|-----------------|
| | 512Mb | 256Mb (x32) | 3.3V/1.8V - 1.8V | 188FBGA | 152FBGA |
| | STZIVID | 512Mb (x16,x32) | 1.8V - 1.8V | 167/202FBGA | 152FBGA |
| | 1Gb | 512Mb (x16,x32) | 1.8V - 1.8V | 167/202FBGA | 168FBGA |
| OweNAND & DDAM | TGD | 1Gb (x32) | 1.8V - 1.8V | - | 168FBGA |
| OneNAND & DRAM | | 512Mb (x16,x32) | 1.8V - 1.8V | - | 152/160/168FBGA |
| | 2Gb | 1Gb (x16,x32) | 1.8V - 1.8V | 167/202FBGA | 152/160/168FBGA |
| | | 2Gb (x32) | 1.8V - 1.8V | - | 152/168FBGA |
| | 4Gb | 1Gb (x16) | 1.8V - 1.8V | 202FBGA | - |

MCP: Flex-OneNAND/DRAM

| Memory | Flex-OneNAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|------------------------|----------------------|---------------------|----------------------|-------------|-------------|
| Flex-OneNAND & DRAM | 8Gb | 2Gb (x32) | 1.8V - 1.8V | 202FBGA | - |

MCP: OneNAND/DRAM/OneNAND

| Memory | Flex-OneNAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | PoP Package |
|-----------------------------|----------------------|---------------------|----------------------|-------------|-------------|
| OneNAND & DRAM & OneDRAM | 2Gb | 1Gb (x16) | 1.8V - 1.8V | | 216FBGA |

MCP: moviNAND/NAND/DRAM

| Memory | movi & NAND Density | DRAM Density (Org.) | Voltages (NAND-DRAM) | MCP Package | Remark |
|-------------|---------------------|---------------------|----------------------|-------------|--------|
| | 512Mb | 256Mb(x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | |
| | STZIVID | 512Mb (x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | |
| | | 256Mb (x16,x32) | 3.0V/1.8V - 1.8V | 107/137FBGA | |
| moviNAND & | 1Gb | 512Mb (x16,x32) | 2.7V/1.8V - 1.8V | 107/137FBGA | |
| NAND & DRAM | | 1Gb (x32) | 1.8V - 1.8V | 137FBGA | |
| | 2Gb | 512Mb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | |
| | 200 | 1Gb (x16,x32) | 1.8V - 1.8V | 107/137FBGA | |
| | 4Gb | 1Gb (x32) | 2.7V - 1.8V | 137FBGA | |

MCP: NOR/UtRAM

| Memory | NOR Density | UtRAM Density (Org.) | Voltages (NOR-UtRAM) | MCP Package | Remark |
|-------------|-------------|----------------------|----------------------|-------------|--------|
| | 512Mb | 128Mb | 1.8V - 1.8V | 107FBGA | |
| | 256Mb | 128Mb | 1.8V - 1.8V | 107FBGA | |
| NOR & Utram | 2001/10 | | 1.8V - 1.8V | 56FBGA | |
| | 128Mb | 64Mb | 1.8V - 1.8V | 84/88FBGA | |
| | | 32Mb | 1.8V - 1.8V | 84/88FBGA | |

MCP: NOR/DRAM

| Memory | NOR Density | DRAM Density (Org.) | Voltages (NOR-DRAM) | Package | Remark |
|------------|-------------|---------------------|---------------------|---------|--------|
| NOR & DRAM | 512Mb | 128Mb (x16) | 1.8V - 1.8V | 103FBGA | |
| | | 256Mb (x16) | 1.8V - 1.8V | 103FBGA | |

Please contact your local Samsung sales representative for latest product offerings. Note: All parts are lead free

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$moviNAND^{\mathsf{TM}}$

moviNAND combines high-density MLC NAND Flash with an MMC controller in a single chip that has an MMC interface. moviNAND delivers dense, cost-effectice storage for embedded applications.

| Density | Package Type | Org. | Vol (V) | Remarks |
|---------|--------------|------|---------|---|
| 2GB | FBGA | x8 | 1.8/3.3 | MMC 4.3 & MMC 4.4 |
| 4GB | FBGA | х8 | 1.8/3.3 | |
| 8GB | FBGA | x8 | 1.8/3.3 | |
| 16GB | FBGA | х8 | 1.8/3.3 | Contact your local Samsung rep for availability and ordering information. |
| 32GB | FBGA | х8 | 1.8/3.3 | ordering internation |
| 64GB | FBGA | х8 | 1.8/3.3 | |

Please contact your local Samsung sales representative for the latest product offerings. Note: All parts are lead free

OneDRAM™

OneDRAM is a dual-port, low-power DRAM with an SRAM buffer interface and is optimal for high-performance, high-density mobile applications.

| Density | Part Number | Package Type | Org. | Vol (V) | Temp. | Speed |
|---------|-------------------|------------------|-----------------------|---------|-----------|-------------|
| | KJA51Z23PC-AAO | 216FBGA (14x14) | A-port: x16 (SDR/DDR) | | | |
| 512Mb | NUAU I ZZOF O-AAO | 2101 DGA (14X14) | B-port: x16 (SDR/DDR) | 1.8V | extended | 133MHz |
| STZIVID | KJA51Y23PC-AA0 | 152FBGA (14x14) | A-port: x16 (SDR/DDR) | 1.00 | exteriueu | 1 JOIVII IZ |
| | NUAUT 125F G-MAG | 1321 DGA (14X14) | B-port: x16 (SDR/DDR) | | | |
| | KJA1GW25PD-EA0 | | A-port: x32SDR | | | 166MHz |
| | NJATOW23FD-LAO | | B-port: x32DDR" | | | |
| | KJA1GZ45PD-EAO | | A-port: x16DDR | | | |
| 1Gb | | 240FBGA (14x14) | B-port: x32DDR" | 1.8V | extended | |
| TGD | KJA1GZ45PD-EAO | 240FBGA (14X14) | A-port: x16DDR | 1.00 | extended | |
| | NOAT UZ40I D-LAO | | B-port: x16DDR" | | | |
| | KJA1GY25PD-EA0 | | A-port: x16SDR | | | |
| | NOTICIZOI D LAC | | B-port: x32DDR" | | | |

Please contact your local Samsung sales representative for the latest product offerings.

Note: All parts are lead free

3.5" Hard Disk Drives

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| Family | Capacity (GB) | RPM | Interface | Buffer | Sector | Model |
|--------|---------------|------|---------------|--------|--------|---------|
| | 80 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD083GJ |
| | 80 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD084GJ |
| | 160 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD161GJ |
| | 160 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD162GJ |
| | 250 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD251HJ |
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD252HJ |
| | 320 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD321HJ |
| F1DT | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD322HJ |
| | 500 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD501IJ |
| | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD502IJ |
| | 640 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD642JJ |
| | 750 | 7200 | SATA-2 | 16 | 512 | HD752LJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HD753LJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 16 | 512 | HD102UJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HD103UJ |
| | 500 | 5400 | SATA 3.0 Gbps | 16 | 512 | HD502HI |
| F2EG | 1 TB | 5400 | SATA 3.0 Gbps | 32 | 512 | HD103SI |
| | 1.5 TB | 5400 | SATA 3.0 Gbps | 32 | 512 | HD154UI |
| | 160 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD164GJ |
| | 250 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD254GJ |
| | 320 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD324HJ |
| | 160 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD163GJ |
| F3 | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD253GJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD323HJ |
| | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD502HJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HD754JJ |
| | 1TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HD103SJ |
| | 250 | - | SATA 3.0 Gbps | 16 | 512 | HD253GI |
| | 320 | - | SATA 3.0 Gbps | 16 | 512 | HD324HI |
| | 500 | - | SATA 3.0 Gbps | 16 | 512 | HD503HI |
| F3EG | 750 | - | SATA 3.0 Gbps | 32 | 512 | HD754JI |
| | 1TB | - | SATA 3.0 Gbps | 32 | 512 | HD105SI |
| | 1.5 TB | - | SATA 3.0 Gbps | 32 | 512 | HD153WI |
| | 2 TB | - | SATA 3.0 Gbps | 32 | 512 | HD203WI |
| | 160 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD165GJ |
| | 160 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD166GJ |
| F4 | 250 | 7200 | SATA 3.0 Gbps | 8 | 512 | HD255GJ |
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD255GJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HD323HJ |

TORAGE

3.5" Enterprise RAID Drives

| Family | Capacity (GB) | RPM | Interface | Buffer | Sector | Model |
|--------|---------------|------|---------------|--------|--------|---------|
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE252HJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE322HJ |
| F1R | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE502IJ |
| rin | 640 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE642JJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HE753LJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HE103UJ |
| | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE253GJ |
| F3R | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HE502HJ |
| | 750 | 7200 | SATA 3.0 Gbps | 32 | 512 | HE754JJ |
| | 1 TB | 7200 | SATA 3.0 Gbps | 32 | 512 | HE103SJ |

2.5" Hard Disk Drives

| Family | Capacity (GB) | RPM | Interface | Buffer | Sector | Model |
|--------------|---------------|------|---------------|--------|--------|---------|
| | 160 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM161GI |
| | 250 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM251HI |
| M7E | 320 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM321HI |
| | 500 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM501JI |
| | 640 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM641JI |
| | 120 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM120JI |
| | 160 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM161JI |
| M7 | 250 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM250II |
| IVI <i>I</i> | 320 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM320HI |
| | 400 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM400HI |
| | 500 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM500GI |
| MP4 | 250 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM250HJ |
| | 320 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM320HJ |
| | 500 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM500JJ |
| | 640 | 7200 | SATA 3.0 Gbps | 16 | 512 | HM640JJ |
| MT2 | 750 | 5400 | SATA 3.0 Gbps | 8 | 512 | HM750LI |
| IVIIZ | 1 TB | 5400 | SATA 3.0 Gbps | 8 | 512 | HM100UI |

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BD-COMBO

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|-----------------|------|---------|-------------|---------------------|
| | BD ROM READ 8X | H/H | Tray | X | TS-HB33A / SH-B083A |
| | | | | 0 | TS-HB33L / SH-B083L |
| | BD ROM READ 12X | H/H | Tray | X | TS-HB43A / SH-B123A |
| SATA | | | | 0 | TS-HB43L / SH-B123L |
| | BD-ROM READ 4X | Slim | Tray | X | TS-LB23A / SN-B043A |
| | | | | | TS-LB23B |
| | | | | | TS-LB23D |
| | | | | 0 | TS-LB23L / SN-B043L |
| | | | | | TS-LB23P |
| | | | Slot | 0 | TS-TB23L |

DVD-W

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| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|---------------|---------------|---------|-------------|---------------------|
| SATA | DVD Write 22X | H/H | Tray | X | TS-H653G |
| | DVD Write 20X | H/H | Tray | Х | TS-H653H |
| | DVD Write 20X | H/H | Tray | X | TS-H653J |
| PATA | DVD Write 22X | H/H | Tray | Х | TS-H662A / SH-S222A |
| | DVD Write 22X | H/H | Tray | X | TS-H663C / SH-S223C |
| SATA | DVD Write 24X | H/H | Tray | X | TS-H663D / SH-S243D |
| SAIA | DVD Write 22X | H/H | Tray | 0 | TS-H653R |
| | DVD Write 16X | H/H | Tray | 0 | TS-H653T |
| PATA | DVD Write 22X | H/H | Tray | 0 | TS-H662L / SH-S222L |
| 0.474 | DVD Write 22X | H/H | Tray | 0 | TS-H663L / SH-S223L |
| SATA | DVD Write 24X | H/H | Tray | 0 | TS-H663N / SH-S243N |
| | | | | | TS-L633B / SN-S083B |
| | | | | X | TS-L633C / SH-S083C |
| | | | | X | TS-L633F / SN-S083F |
| | | | Tray | | TS-L633J |
| | | Slim | | | TS-L633N / SN-S083N |
| | | | | 0 | TS-L633R / SN-S083R |
| SATA | DVD Write 8X | | | | TS-L633Y |
| | | | Olet | X | TS-T633C / SN-T083C |
| | | | Slot | 0 | TS-T633P |
| | | | Tress | V | TS-U633F |
| | | Lillana Clina | Tray | X | TS-U633J / SU-S083J |
| | | Ultra Slim | Olat | V | TS-D633A |
| | | | Slot | X | TS-D633C |

RAGE

DVD-W Slim External

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|--------------|------------|---------|-------------|----------|
| USB 2.0 | DVD Write 8X | Slim | Tray | X | SE-S084C |
| | | Ultra Slim | Tray | X | SE-S084D |
| | | Slim | Tray | X | SE-S084F |
| | | | Slot | 0 | SE-T084P |

DVD-ROM

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|---------|-----------|---------|-------------|---------------------|
| SATA | DVD 16X | H/H | Tray | X | TS-H353C / SH-D163J |
| | DVD 8X | Slim | Tray | X | TS-L333B |
| | | | | | TS-L333D |
| | DVD 8X | Utra Slim | Tray | X | TS-U333A |

DVD-W Loader

| Interface | Speed | Туре | Loading | Lightscribe | Medel |
|-----------|--------|------|---------|-------------|----------|
| PATA | DVD 8X | H/H | Tray | Χ | TS-P632F |

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